

SL210A

Technical Data Data Sheet N1955, Rev. A RoHS 🗭

SL210A SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Circuit Diagram



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=115°C, rectangular wave form	2	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T_c = 25 °C	70	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 2A, Pulse, T _J = 25 °C	0.74	0.78	V
	V _{F2}	@ 2A, Pulse, T _J = 125℃	0.61	0.68	V
Reverse Current*	I _{R1}	@ V _R = rated V _{R,} T _J = 25℃	0.01	0.1	mA
	I _{R2}	@V _R = rated V _{R,} T _J = 100°C	-	2.0	mA
Junction Capacitance	Cj	@V _R = 5.0 V, Tc=25℃ f _{SIG} = 1MHz	90	200	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 µs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	$R_{ heta JL}$	DC operation	17	°C/W
Typical Thermal Resistance Junction to Ambient	R _{0JA}	DC operation	75	°C/W
Approximate Weight	wt	-	0.06	g

Ratings and Characteristics Curves

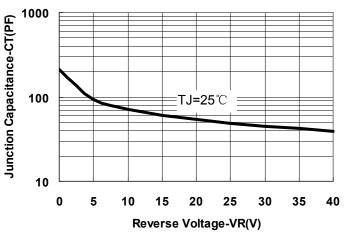


Fig.1-Typical Junction Capacitance

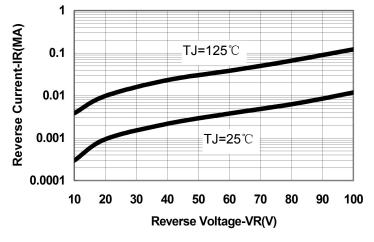
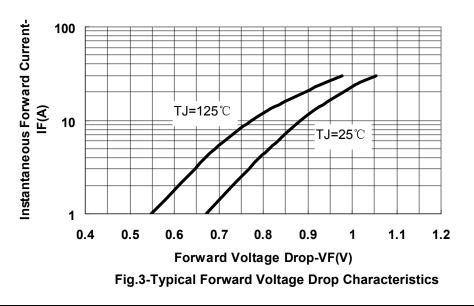


Fig.2-Typical Values Of Reverse Current



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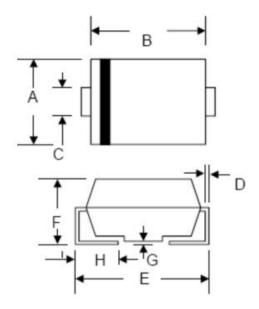


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Mechanical Dimensions SMA



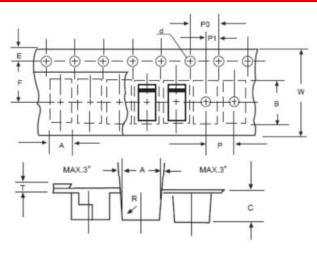
SYMBOL	Millir	neters	Inc	hes
STMBOL	Min.	Max.	Min.	Max.
А	2.40	2.84	0.094	0.112
В	3.99	4.75	0.157	0.187
С	1.05	1.70	0.041	0.067
D	0.15	0.51	0.006	0.020
E	4.80	5.66	0.189	0.223
F	1.90	2.95	0.075	0.116
G	0.05	0.203	0.002	0.008
н	0.76	1.52	0.030	0.600

Ordering Information

Device	Package	Shipping
SL210A	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification SMA



SYMBOL	Millimeters		
STINIBUL	Min.	Max.	
A	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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Marking Diagram

SL210A

XXXXX

Where XXXXX is YYWWL

- = Device Type
- = Forward Current (2A) = Reverse Voltage (100V) = Package type = Year ŴŴ = Week
 - = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0



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